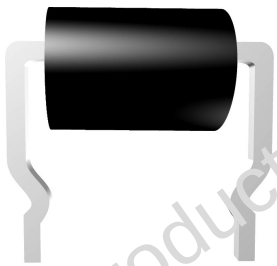
STPS5L40-C2

POWER SCHOTTKY RECTIFIER

MAIN PRODUCT CHARACTERISTICS

$I_{F(AV)}$	5 A
V_{RRM}	40 V
Tj (max)	150°C
V_F (max)	0.44 V



DO-201AD
STPS5L40-C2

FEATURES AND BENEFITS

- NEGLIGIBLE SWITCHING LOSSES
- LOW FORWARD VOLTAGE DROP FOR HIGHER EFFICIENCY.
- LOW THERMAL RESISTANCE
- AVALANCHE CAPABILITY SPECIFIED

DESCRIPTION

Axial Power Schottky rectifier suited for Switch Mode Power Supplies and high frequency inverters.

Packaged in DO-201AD, this device is intended for use in low voltage output for small battery chargers & consumer SMPS such as DVD and Set-Top-Box.

ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value	Unit
V_{RRM}	Repetitive peak reverse voltage		40	V
$I_{F(RMS)}$	RMS forward current		15	A
$I_{F(AV)}$	Average forward current	Tl = 100°C δ = 0.5	5	A
I_{FSM}	Surge non repetitive forward current	Half wave, single phase tp = 10 ms	150	A
P_{ARM}	Repetitive peak avalanche power	tp = 1µs Tj = 25°C	2700	W
T_{stg}	Storage temperature range		- 65 to + 150	°C
Tj	Maximum operating junction temperature *		150	°C
dV/dt	Critical rate of rise of reverse voltage (rated V_R, Tj = 25°C)		10000	V/µs

* : $\frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$ thermal runaway condition for a diode on its own heatsink

THERMAL PARAMETERS

Symbol	Parameter		Value	Unit
$R_{th(j-a)}$	Junction to ambient		75	°C/W
$R_{th(j-l)}$	Junction to leads	Lead length = 10 mm	15	°C/W

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Tests conditions		Min.	Typ.	Max.	Unit
I_R *	Reverse leakage current	Tj = 25°C	$V_R = V_{RRM}$			0.2	mA
		Tj = 100°C			8	25	
		Tj = 125°C			25	75	
V_F *	Forward voltage drop	Tj = 25°C	I_F = 5 A		0.44	0.50	V
		Tj = 100°C			0.40	0.46	
		Tj = 125°C			0.38	0.44	

Pulse test : * tp = 380 µs, δ < 2%

To evaluate the maximum conduction losses use the following equation:

$P = 0.34 \times I_{F(AV)} + 0.028 \times I_F{}^2{}_{(RMS)}$

Fig. 1: Conduction losses versus average current.

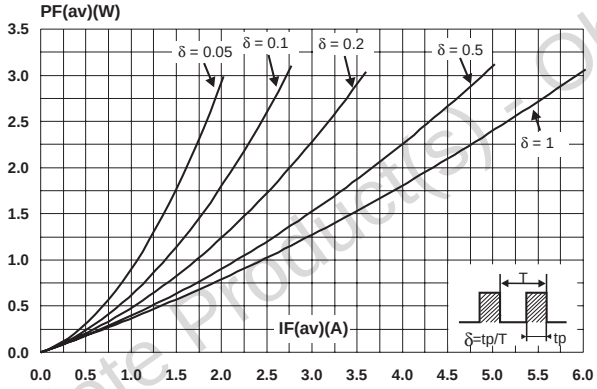


Fig. 2: Average forward current versus ambient temperature (δ = 0.5).

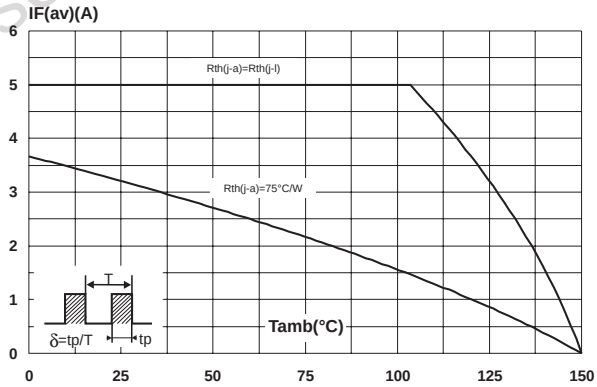


Fig. 3: Normalized avalanche power derating versus pulse duration.

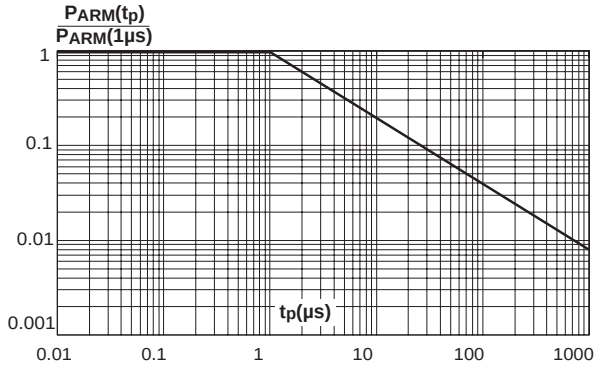


Fig. 4: Normalized avalanche power derating versus junction temperature.

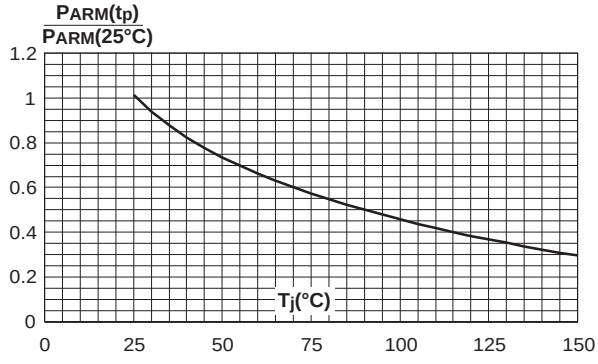


Fig. 5: Non repetitive surge peak forward current versus overload duration (maximum values).

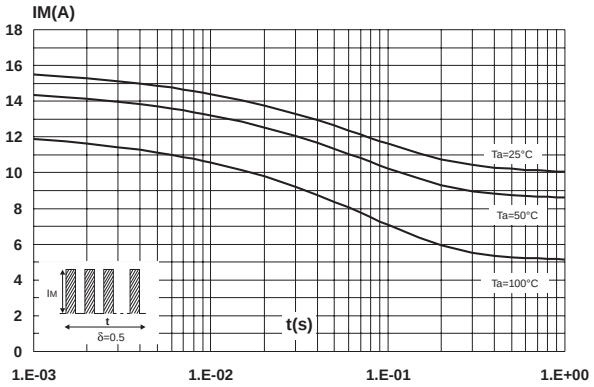


Fig. 6: Relative variation of thermal impedance junction to ambient versus pulse duration.

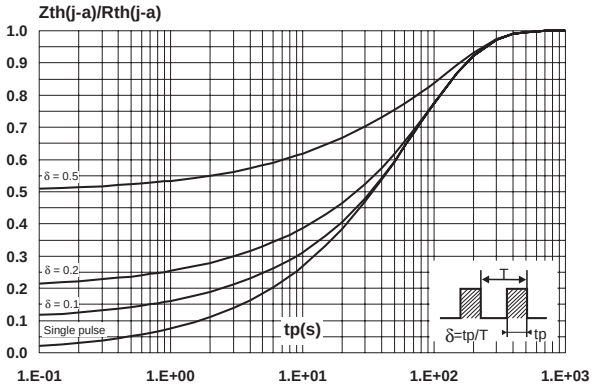


Fig. 7: Reverse leakage current versus reverse voltage applied (typical values).

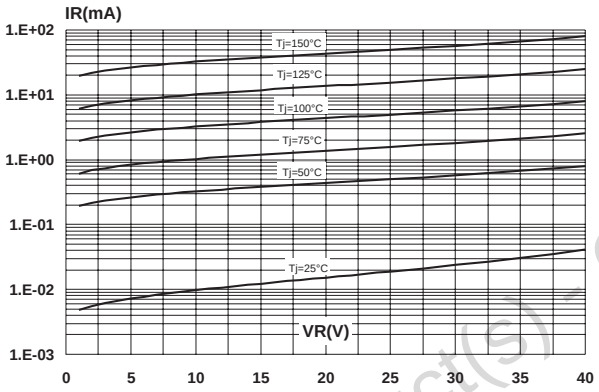


Fig. 8: Junction capacitance versus reverse voltage applied (typical values).

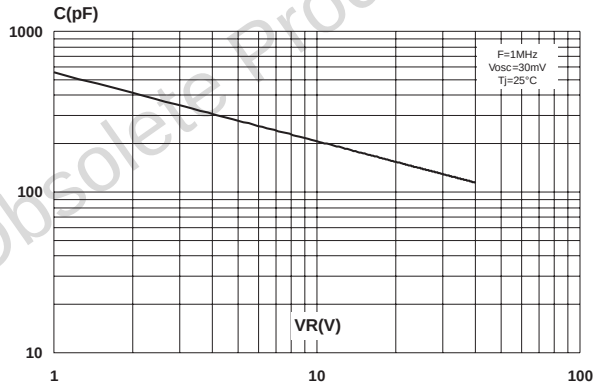


Fig. 9-1: Forward voltage drop versus forward current (low level).

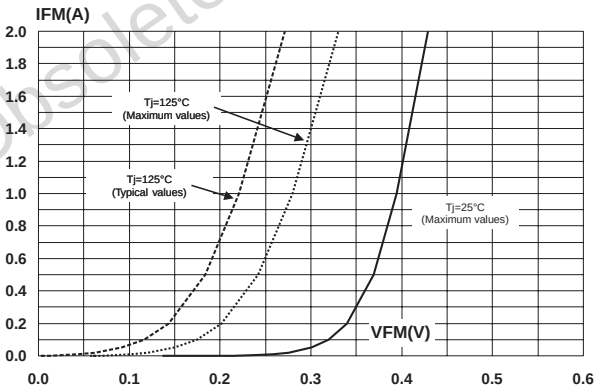


Fig. 9-2: Forward voltage drop versus forward current (high level).

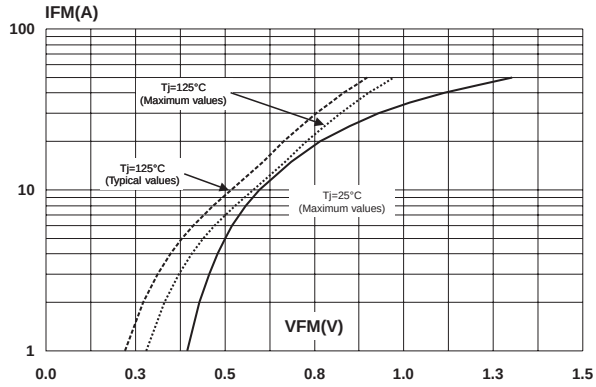


Fig. 10: Thermal resistance junction to ambient versus copper surface under each lead (epoxy printed board FR4, Cu = 35µm).

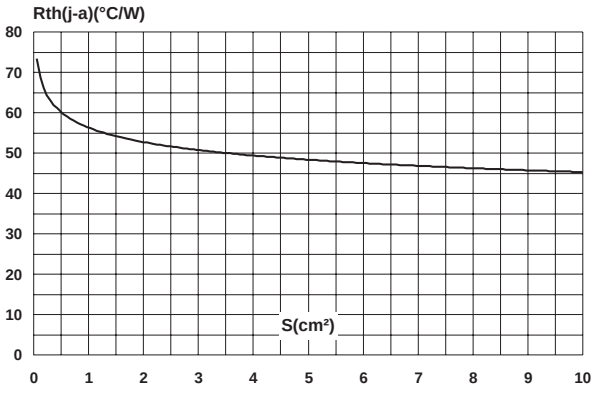
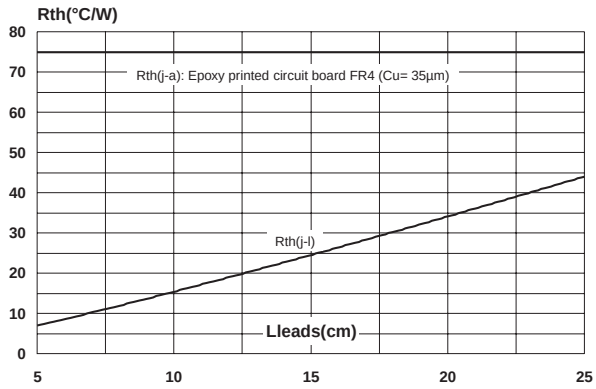
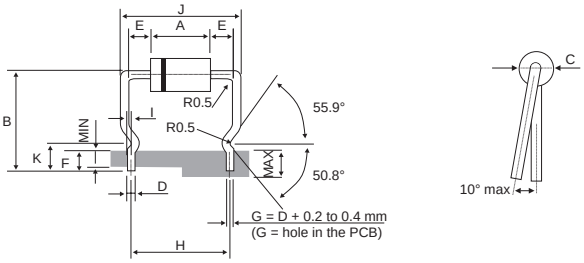


Fig. 11: Thermal resistances versus leads length.



PACKAGE MECHANICAL DATA

DO-201AD plastic



REF.	DIMENSIONS					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			9.5			0.374
B	13.75		17.75	0.541		0.699
C			5.3			0.208
D			1.3			0.051
E		3.53			0.139	
F	2.4	3.15	3.9	0.094	0.124	0.153
G		1.6			0.063	
H	14.9		15.6	0.587		0.614
I	0.5	0.6	0.7	0.019	0.024	0.027
J		18.78			0.739	
K	3.8		4.8	0.150		0.189

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STPS5L40-C2	STPS5L40	DO-201AD	1.12g	500	Ammopack

- WHITE BAND INDICATES CATHODE
- EPOXY MEETS UL94,V0